

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included. When implemented in P-Spice, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in Application Note AN609, "Thermal Simulation of Power MOSFETs on the P-Spice Platform."

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	10.1698	N/A	5.5614
RT2	23.0213	N/A	21.5175
RT3	29.1321	N/A	4.5847
RT4	47.6768	N/A	6.3364
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	302.8012 u	N/A	1.8310 m
CT2	55.4643 m	N/A	3.5684 m
CT3	4.0123 m	N/A	93.5894 u
CT4	1.4844	N/A	2.5501 m

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

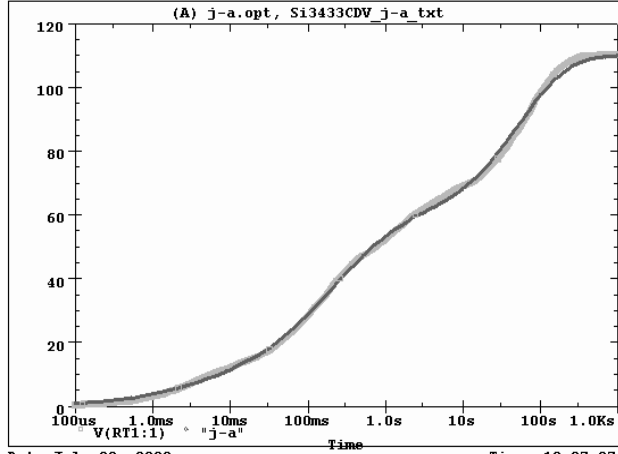
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RF1	12.3928	N/A	5.7471
RF2	31.7669	N/A	18.0473
RF3	20.1954	N/A	12.5000
RF4	45.6449	N/A	1.7056
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	294.9757 u	N/A	88.4623 u
CF2	3.7227 m	N/A	827.1072 u
CF3	66.2577 m	N/A	3.2159 m
CF4	1.4759	N/A	419.2380 m

Note

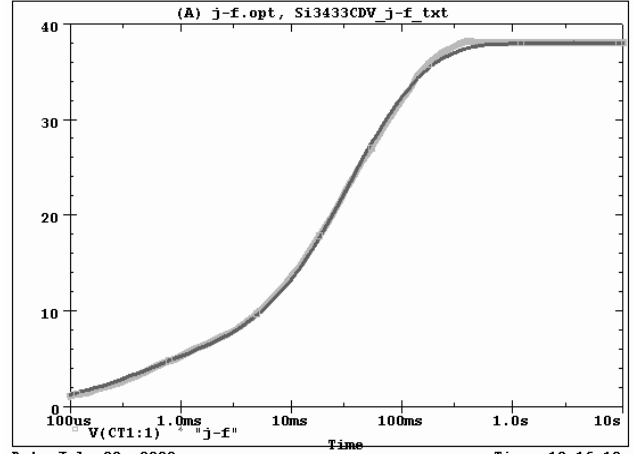
NA indicates not applicable



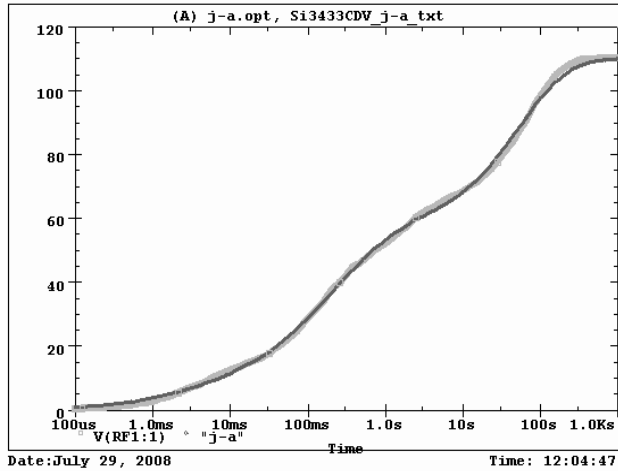
Si3433CDV Tank j-a Temperature:27.0



Si3433CDV Tank j-f Temperature:27.0



Si3433CDV Filter j-a Temperature:27.0



Si3433CDV Filter j-f Temperature:27.0

